

TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (PCT PROCESS)

2SA1620

AUDIO FREQUENCY AMPLIFIER APPLICATIONS

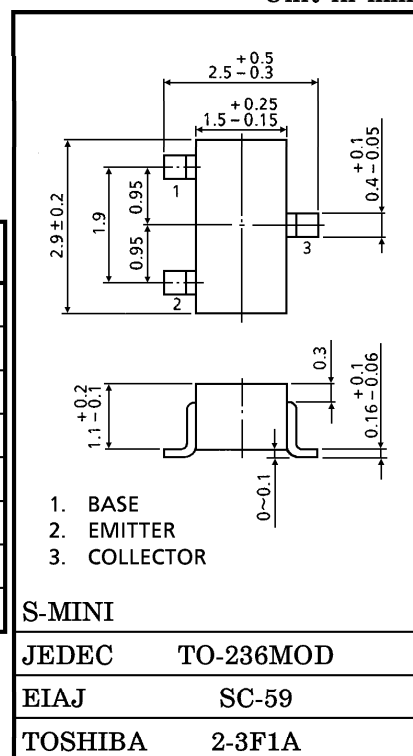
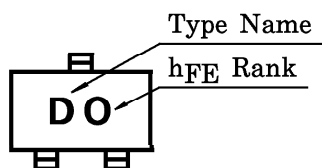
Unit in mm

- Complementary to 2SC4209

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-80	V
Collector-Emitter Voltage	V_{CEO}	-80	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-300	mA
Base Current	I_B	-60	mA
Collector Power Dissipation	P_C	200	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55~150	$^\circ\text{C}$

Marking

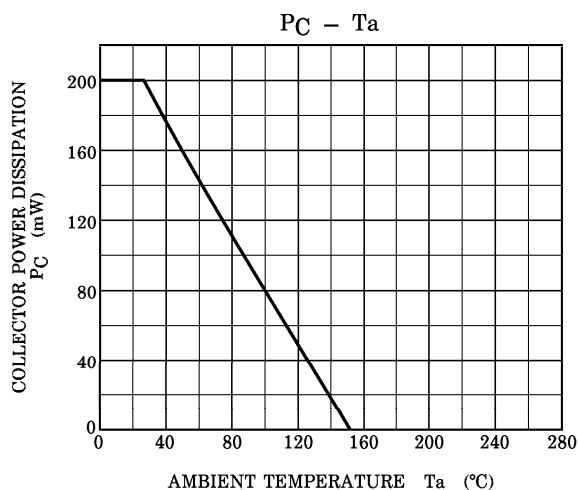
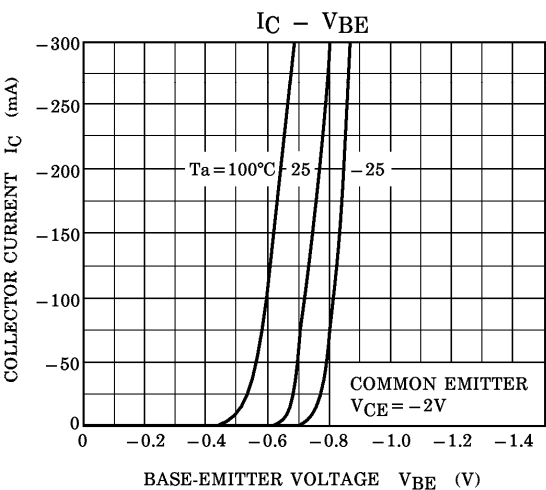
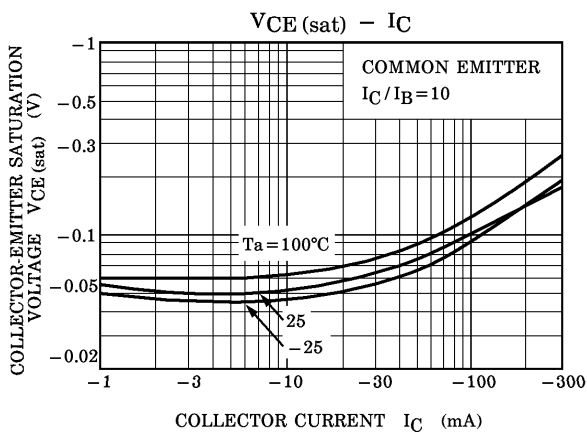
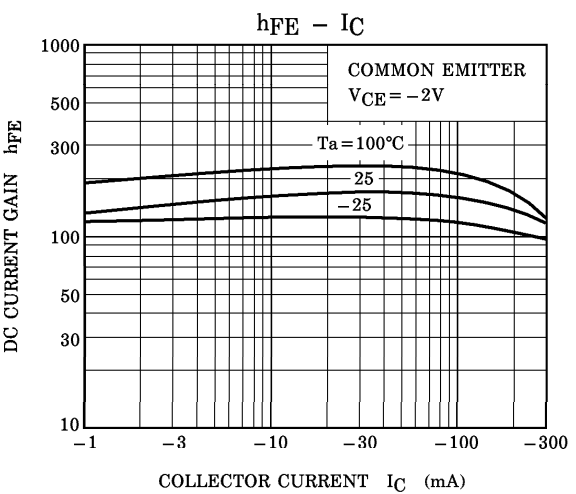
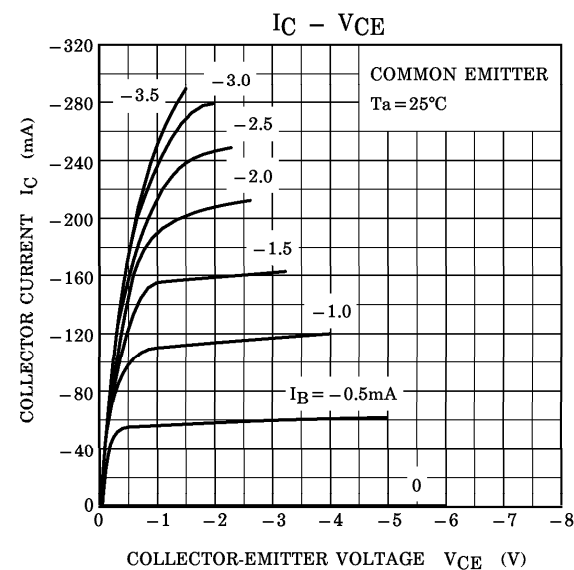


Weight : 0.012g

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = -50\text{V}, I_E = 0$	—	—	-0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -5\text{V}, I_C = 0$	—	—	-0.1	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -5\text{mA}, I_B = 0$	-80	—	—	V
DC Current Gain	$h_{FE(1)}$ (Note)	$V_{CE} = -2\text{V}, I_C = -50\text{mA}$	70	—	240	
	$h_{FE(2)}$	$V_{CE} = -2\text{V}, I_C = -200\text{mA}$	40	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -200\text{mA}, I_B = -20\text{mA}$	—	—	-0.4	V
Base-Emitter Voltage	V_{BE}	$V_{CE} = -2\text{V}, I_C = -5\text{mA}$	-0.55	—	-0.8	V
Transition Frequency	f_T	$V_{CE} = -10\text{V}, I_C = -10\text{mA}$	70	100	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10\text{V}, I_E = 0, f = 1\text{MHz}$	—	14	—	pF

Note : h_{FE} Classification, O : 70~140, Y : 120~240



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